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| <b>INFORMATION DISCLOSURE<br/>STATEMENT BY APPLICANT</b> | Application No.      | 10/568,229        |
|  | Filing Date          | February 14, 2006 |
|  | First Named Inventor | Vivian Alberts    |
|  | Art Unit             | 1793              |
| (Multiple sheets used when necessary)                    | Examiner             | Ip, Sikyin        |
| SHEET 1 OF 2   | Attorney Docket No.  | DMKISCH.003APC    |

| U.S. PATENT DOCUMENTS |          |   |                                |                               |  |
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| Examiner Initials     | Cite No. | Document Number<br>Number - Kind Code (if known)<br>Example: 1,234,567 B1 | Publication Date<br>MM-DD-YYYY | Name of Patentee or Applicant | Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear |
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| FOREIGN PATENT DOCUMENTS |          |  |                                |                               |  |                |
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| NON PATENT LITERATURE DOCUMENTS |          |  |                |
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| Examiner Initials               | Cite No. | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.                              | T <sup>1</sup> |
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|--------------------|-----------------|
| Examiner Signature | Date Considered |
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\***Examiner:** Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

T<sup>1</sup> - Place a check mark in this area when an English language Translation is attached.

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